

CY7C287

64K x 8 Reprogrammable Registered PROM

Features

- CMOS for optimum speed/power
- Windowed for reprogrammability
- High speed
 - —t_{SA} = 45 ns
 - $-t_{CO} = 15 \text{ ns}$
- Low power
- —120 mA
- · On-chip, edge-triggered output registers
- Programmable synchronous or asynchronous output enable
- EPROM technology, 100% programmable
- + 5V \pm 10% V_{CC}, commercial and military
- TTL-compatible I/O
- Slim 300-mil package
- Capable of withstanding >2001V static discharge

Functional Description

The CY7C287 is a high-performance 64K x 8 CMOS PROM. The CY7C287 is equipped with an output register and an out-

put enable that can be programmed to be synchronous (\overline{E}_S) or asynchronous (\overline{E}). It is available in a 28-pin, 300-mil package. The address set-up time is 45 ns and the time from clock HIGH to output valid is 15 ns.

The CY7C287 is available in a cerDIP package equipped with an erasure window to provide reprogrammability. When exposed to UV light, the PROM is erased and can be reprogrammed. The memory cells utilize proven EPROM floating-gate technology and byte-wide intelligent programming algorithms.

The CY7C287 offers the advantage of low power, superior performance, and programming yield. The EPROM cell requires only 12.5V for the supervoltage and low current requirements allow for gang programming. The EPROM cells allow for each memory location to be 100% tested with each cell being programmed, erased, and repeatedly exercised prior to encapsulation. Each PROM is also tested for AC performance to guarantee that the product will meet DC and AC specification limits after customer programming.

Reading the CY7C287 is accomplished by placing an active LOW signal on $\overline{E}/\overline{E}_S$. The contents of the memory location addressed by the address lines (A₀ – A₁₅) will become available on the output lines (O₀ – O₇) on the next rising of CP.





Selection Guide

		7C287–45	7C287–55	7C287-65
Maximum Set-Up Time (ns)		45	55	65
Maximum Clock to Output (ns)		15	20	25
Maximum Operating Current (mA)	Com'l	120	120	120
	Mil		150	150

Maximum Ratings

(Above which the useful life may be impaired. For user guide-lines, not tested.)
Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied
Supply Voltage to Ground Potential0.5V to +7.0V
DC Voltage Applied to Outputs in High Z State0.5V to +7.0V
DC Input Voltage3.0V to +7.0V
DC Program Voltage

UV Exposure	7258 Wsec/cm ²
Static Discharge Voltage	>2001V
(per MIL-STD-883, Method 3015.2)	
Latch-Up Current	>200 mA

Operating Range

Range	Ambient Temperature	v _{cc}
Commercial	0°C to +70°C	5V ± 10%
Industrial ^[1]	–40°C to +85°C	5V ± 10%
Military ^[2]	–55°C to +125°C	5V ± 10%

Electrical Characteristics Over the Operating Range^[3]

				7C28	37–45	7C28	87–55	7C28	87–65	
Parameter	Description	Test Conditions		Min.	Max.	Min.	Max.	Min.	Max.	Unit
V _{OH}	Output HIGH Voltage	V_{CC} = Min., I_{OH} = -2.0 mA		2.4		2.4		2.4		V
V _{OL}	Output LOW Voltage	V_{CC} = Min., I_{OL} = 8.0 mA	Com'l		0.4		0.4		0.4	V
			Mil				0.4		0.4	
V _{IH}	Input HIGH Voltage	Guaranteed Input Logical Voltage for Inputs	HIGH	2.0	V _{CC}	2.0	V _{CC}	2.0	V _{CC}	V
V _{IL}	Input LOW Voltage	Guaranteed Input Logical Voltage for Inputs	LOW		0.8		0.8		0.8	V
I _{IX}	Input Load Current	$GND \le V_{IN} \le V_{CC}$		-10	+10	-10	+10	-10	+10	μΑ
V _{CD}	Input Diode Clamp Voltage				Note 4					
I _{OZ}	Output Leakage Current	GND ≤ V _{OUT} ≤ V _{CC} , Output Disabled		-40	+40	-40	+40	-40	+40	μΑ
I _{OS}	Output Short Circuit Current	V _{CC} = Max., V _{OUT} = GND	5]	-20	-90	-20	-90	-20	-90	mA
I _{CC}	V _{CC} Operating	V _{CC} = Max., Com'l			120		120		120	mA
	Supply Current	I _{OUT} = 0 mA	Mil				150		150	
V _{PP}	Programming Supply Voltage			12	13	12	13	12	13	V
I _{PP}	Programming Supply Current				50		50		50	mA
V _{IHP}	Input HIGH Programming Voltage			3.0		3.0		3.0		V
V _{ILP}	Input LOW Programming Voltage				0.4		0.4		0.4	V

Notes:

Contact a Cypress representative for industrial temperature range specifications. 1.

T_A is the "instant on" case temperature industrial temperature range specifications.
See the last page of this specification for Group A subgroup testing information.
See Introduction to CMOS PROMs for general information on testing.
Short circuit test should not exceed 30 seconds.



Capacitance^[4]

Parameter	Description	Test Conditions	Max.	Unit
C _{IN}	Input Capacitance	$T_A = 25^{\circ}C, f = 1 \text{ MHz},$	10	pF
C _{OUT}	Output Capacitance	$V_{CC} = 5.0V$	10	pF

AC Test Loads and Waveform^[4]



Switching Characteristics Over the Operating Range^[3,4]

		7C287–45		7C287–55		7C287–65		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Unit
t _{SA}	Address Set-Up to Clock HIGH	45		55		65		ns
t _{HA}	Address Hold from Clock HIGH	0		0		0		ns
t _{CO}	Clock HIGH to Output Valid		15		20		25	ns
t _{HZE}	Output High Z from E		15		20		25	ns
t _{DOE}	Output Valid from E		15		20		25	ns
t _{PWC}	Clock Pulse Width	15		20		25		ns
t _{SEs} ^[6]	E _S Set-Up to Clock HIGH	12		15		18		ns
t _{HEs} ^[6]	E _S Hold from Clock HIGH	5		8		10		ns
t _{HZC} ^[6]	Output High Z from CLK/E _S		20		25		30	ns
t _{COs} ^[6]	Output Valid from CLK/E _S		20		25		30	ns

Notes:

6. Parameters with synchronous \overline{E}_{S} option.



Switching Waveform



Erasure Characteristics

Wavelengths of light less than 4000 Angstroms begin to erase the CY7C287 in the windowed package. For this reason, an opaque label should be placed over the window if the PROM is exposed to sunlight or fluorescent lighting for extended periods of time.

The recommended dose of ultraviolet light for erasure is a wavelength of 2537 angstroms for a minimum dose (UV intensity multiplied by exposure time) of 25 Wsec/cm2. For an ultraviolet lamp with a 12 mW/cm² power rating, the exposure time would be approximately 35 minutes. The CY7C287 needs to

be within 1 inch of the lamp during erasure. Permanent damage may result if the PROM is exposed to high-intensity UV light for an extended period of time. 7258 Wsec/cm² is the recommended maximum dosage.

Programming Modes

Programming support is available from Cypress as well as from a number of third-party software vendors. For detailed programming information, including a listing of software packages, please see the PROM Programming Information located at the end of this section. Programming algorithms can be obtained from any Cypress representative.

	Pin Function ^[7]				
Mode: Read or Output Disable	СР	A ₁₄	Ē, Ē _S	A ₁₅	0 ₇ – 0 ₀
Synchronous Read	V _{IL} /V _{IH}	A ₁₄	V _{IL}	A ₁₅	O ₇ - O ₀
Output Disable – Asynchronous	Х	A ₁₄	V _{IH}	A ₁₅	High Z
Output Disable – Synchronous	V _{IL} /V _{IH}	A ₁₄	V _{IH}	A ₁₅	High Z
Mode: Other	PGM	LATCH	VFY	V _{PP}	D ₇ – D ₀
Program	V _{ILP}	V _{ILP}	V _{IHP}	V _{PP}	$D_7 - D_0$
Program Verify	V _{IHP}	V _{ILP}	V _{ILP}	V _{PP}	O ₇ - O ₀
Program Inhibit	V _{IHP}	V _{ILP}	V _{IHP}	V _{PP}	High Z
Blank Check	V _{IHP}	V _{ILP}	V _{ILP}	V _{PP}	Zeros

Table 1. CY7C287 Mode Selection

Notes:

7. X = "don't care" but not to exceed V_{CC} \pm 5%. X can be V_{IL} ir V_{IH}.





Figure 1. Programming Pinouts

Architecture Configuration Bits

Architecture Bit	Device	Arc	hitecture Verify D ₀	Function
E/E _S	7C287	D ₀	0 = Erased	Asynchronous Output Enable (Pin 20 = \overline{E})
			1 = PGMED	Synchronous Output Enable (Pin 20 = \overline{E}_S)

Bit Map

Programmer Address (Hex.)	RAM Data
0000	Data
FFFF 10000	Data Control Byte

Architecture Byte (10000H) D7 D0

C7 C6 C5 C4 C3 C2 C1 C0



Ordering Information^[8]

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
45	CY7C287-45JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C287-45PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C287-45WC	W22	28-Lead (300-Mil) Windowed CerDIP	
55	CY7C287-55JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C287-55PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C287-55WC	W22	28-Lead (300-Mil) Windowed CerDIP	
	CY7C287-55DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C287-55LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
	CY7C287-55QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	
	CY7C287-55WMB	W22	28-Lead (300-Mil) Windowed CerDIP	
65	CY7C287-65JC	J65	32-Lead Plastic Leaded Chip Carrier	Commercial
	CY7C287-65PC	P21	28-Lead (300-Mil) Molded DIP	
	CY7C287-65WC	W22	28-Lead (300-Mil) Windowed CerDIP	
	CY7C287-65DMB	D22	28-Lead (300-Mil) CerDIP	Military
	CY7C287-65LMB	L55	32-Pin Rectangular Leadless Chip Carrier	
	CY7C287-65QMB	Q55	32-Pin Windowed Rectangular Leadless Chip Carrier	
	CY7C287-65WMB	W22	28-Lead (300-Mil) Windowed CerDIP	

Notes:

8. Most of these products are available in industrial temperature range. Contact a Cypress representative for specifications and product availability.

MILITARY SPECIFICATIONS Group A Subgroup Testing

DC Characteristics

Parameter	Subgroups
V _{OH}	1, 2, 3
V _{OL}	1, 2, 3
V _{IH}	1, 2, 3
V _{IL}	1, 2, 3
I _{IX}	1, 2, 3
I _{OZ}	1, 2, 3
I _{CC}	1, 2, 3

Switching Characteristics

Parameter	Subgroups
t _{SA}	7, 8, 9, 10, 11
t _{HA}	7, 8, 9, 10, 11
t _{CO}	7, 8, 9, 10, 11
t _{DOE}	7, 8, 9, 10, 11
t _{PWC}	7, 8, 9, 10, 11

Document #: 38-00363



CY7C287

Package Diagrams



32-Lead Plastic Leaded Chip Carrier J65



32-Pin Rectangular Leadless Chip Carrier L55 MIL-STD-1835 C-12

32-Pin Windowed Rectangular Leadless Chip Carrier Q55 MIL-STD-1835 C-12







Package Diagrams

28-Lead (300-Mil) Molded DIP P21



28-Lead (300-Mil) Windowed CerDIP W22 MIL-STD-1835 D-15 Config.A



© Cypress Semiconductor Corporation, 1994. The information contained herein is subject to change without notice. Cypress Semiconductor Corporation assumes no responsibility for the use of any circuitry other than circuitry embodied in a Cypress Semiconductor product. Nor does it convey or imply any license under patent or other rights. Cypress Semiconductor does not authorize its products for use as critical components in life-support systems where a malfunction or failure may reasonably be expected to result in significant injury to the user. The inclusion of Cypress Semiconductor products in life-support systems where a malfunction or failure may reasonably be expected to result in significant injury to the user. The inclusion of charges.